# NSN 5961-01-081-8123

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## Inclosure Material:

Plastic

Internal Configuration:

Field effect

# Joint Electronic Device Engineering Council/jedec/case Outline Designation:

To-106

#### **Mounting Method:**

Terminal

## Semiconductor Material:

Silicon

### Voltage Rating In Volts Per Characteristic:

30.0 gate to source voltage

### **Current Rating Per Characteristic:**

50.00 milliamperes gate current

#### Maximum Operating Tempurature Per Measurement Point:

125.0 degrees celsius ambient air

# Terminal Type And Quantity:

3 uninsulated wire lead

Shelf Life:

N/a

### Unit Of Measure:

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#### Demilitarization:

Yes - demil/mli

### Fiig:

A110a0